## **Typical Operating Procedure**

- 1. Remove Plexiglas cover and place in safe location.
- 2. Ensure valve lever is set to backing. [Fig 1]
- 3. Ensure vacuum gauges are OFF.
- 4. Depress Air Admit button. [Fig 2]
- 5. Vent with slow source of  $N_2$  gas on south wall of lab. [Fig 3]
- 6. When fully vented press Air Admit valve. [Fig 2]
- 7. Carefully place bell jar on "bell jar cradle for Edwards".
- 8. Close  $N_2$  value on wall. [Fig 3]
- 9. Check crystal monitor health (TC/CHK) [Fig 4] (Note: failure ~50%)
- 10. Open cooling water for crystal half-turn (lower right side) [Fig 5]
- 11. Remove platen from chamber and attach samples.
- 12. Add source material(s) as necessary.
- 13. Rotate boat/rod to contact pad [Fig 6] with source knob. [Fig 7] Note: Rotation may be difficult. Only turn counter-clockwise.
- 14. Insert new glass slide in window.
- 15. Close shutter.
- 16. Remove debris from sample platen using compressed  $N_2$ .
- 17. Return platen to chamber, aligning shadow on platen to crystal monitor in chamber.
- 18. Carefully return bell jar to baseplate, press down and twist to seal.
- **19.** Push valve lever [Fig 1] in; turn counterclockwise to roughing.
- 20. Allow a few minutes to pump to  $10^{-1}$  on Pirani gauge.
- 21. Turn valve lever clockwise to backing. [Fig 1]
- 22. Slowly turn valve lever [Fig 1] further clockwise to roughing to lift plate in bottom of chamber.

*Note*: *System may be left pumping overnight at this stage* 

- 23. Ensure penning gauge is on Range 1. Turn gauge ON.
- 24. When pressure is <  $2 \times 10^{-5}$  mbar, switch to Range 2, 3 as needed.Range 1: P =  $10^{-2} 10^{-5}$  mbarRange 2: P =  $2 \times 10^{-5} 10^{-6}$  mbarRange 3: P =  $2 \times 10^{-6} 10^{-7}$  mbar
- 25. Add liquid nitrogen (LN2) to cold trap (insert metal funnel on left side of system) [Fig 8]
- 26. Allow pressure to drop to  $\sim 1.5 \times 10^{-6}$  using (Range 3).
- 27. Perform deposition sequence of first material. Note: See Material-Specific Deposition Notes section.
- 28. Rotate source knob to second material.
- 29. Perform deposition of second material, and others as necessary.
- 30. When deposition is complete, turn pressure gauges off.
- **31. Turn valve lever** [Fig 1] counterclockwise to backing.
- 32. Turn water off (lower right side of machine) [Fig 5]
- 33. Allow system to cool for at least 15-30 min.
- 34. Open  $N_2$  value on wall. [Fig 3]
- 35. Depress Air Admit button. [Fig 2]
- 36. When chamber is vented close  $N_2$  value on wall.  $\cite{Fig}$  3]
- 37. Press Air Admit button. [Fig 2]
- 38. Remove bell jar and samples.
- 39. Return platen to chamber.

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Fig 3



Fig 4

Fig 5



![](_page_0_Picture_53.jpeg)

![](_page_0_Picture_54.jpeg)

- 40. Carefully return bell jar to baseplate, press down and twist to seal.
- 41. While pushing valve lever [Fig 1] in, turn *counterclockwise* to roughing.
- 42. Wait 2 min.
- 43. Rotate valve lever clockwise [Fig 1] to backing.Note: It is always best to leave vacuum systems under vacuum when not in use for extended periods of time.

## **Material-Specific Deposition Notes**

## Chromium

- 1. Push Thickness 1 [Fig 10] on growth control panel.
- 2. When program light is on, enter parameters using keypad: Density: 720, press E. Note: chromium (7.20 g/cm<sup>3</sup>) z-Ratio: 0305, press E. Note: chromium (0.305 z-ratio) Tooling: 50, press E. (50%)
- 3. Switch penning gauge to Range 2.
- 4. Push LT button. [Fig 9]
- 5. Preheat sequence: [Fig 9]
  - a. Increase power slowly to 50%; remain for 3 min.
  - b. Increase power slowly to 70%; remain for 1 min.
  - c. Increase power slowly to 90%.
- 6. Press Zero button [Fig 4] and open shutter.
- Increase power [Fig 9] slowly as needed to maintain rate.
  Note: Deposition rate for chromium ~1.5-2.5Å/s.
- 8. When final thickness obtained, close shutter. [Fig 8]
- 9. Reduce power <u>slowly</u> to 0%. [Fig 9]
- 10. Press LT button. [Fig 9]

## Indium

- 1. Push Thickness 1 [Fig 10] on growth control panel
- 2. When program light is on, enter parameters using keypad: Density: 730, press E. Note: Indium (7.30 g/cm<sup>3</sup>) z-Ratio: 0841, press E. Note: Indium (0.841 z-ratio) Tooling: 50, press E. (50%)
- 3. Turn penning gauge to Range 2.
- 4. Press LT button. [Fig 9]
- 5. Preheat sequence: [Fig 9]
  - a. Increase power slowly to 50%, remain for 3 min
  - b. Increase power slowly to 70%, remain for 1 min
  - c. Increase power slowly to 90%
- 6. Press Zero button [Fig 4] and open shutter.
- 7. Increase power [Fig 9] slowly as needed to maintain rate. Note: Deposition rate for indium ~15-20Å/s.
- 8. When final thickness is obtained, close shutter. [Fig 8]
- 9. Reduce power <u>slowly</u> to 0%. [Fig 9]
- 10. Press LT button. [Fig 9]

**Note**: See Technical Data for Depositing Thin Films Under Vacuum table for additional material information.

![](_page_1_Picture_36.jpeg)

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![](_page_1_Picture_38.jpeg)

![](_page_1_Picture_39.jpeg)

![](_page_1_Picture_40.jpeg)

![](_page_1_Picture_41.jpeg)

![](_page_1_Picture_42.jpeg)

![](_page_1_Picture_43.jpeg)

![](_page_1_Figure_44.jpeg)

![](_page_1_Picture_45.jpeg)